

### IGBT MODULE (S series) 1400V / 25A / PIM



#### ■ Features

- Low  $V_{CE(sat)}$
- Compact Package
- P.C. Board Mount Module
- Converter Diode Bridge Dynamic Brake Circuit

#### ■ Applications

- Inverter for Motoe Drive
- AC and DC Servo Drive Amplifier
- Uninterruptible Power Supply

#### ■ Maximum ratings and characteristics

● Absolute maximum ratings ( $T_c=25^\circ\text{C}$  unless without specified)

Item	Symbol	Condition	Rating	Unit	
Inverter	Collector-Emitter voltage	$V_{CES}$	1400	V	
	Gate-Emitter voltage	$V_{GES}$	$\pm 20$	V	
	Collector current	$I_c$	Continuous	$T_c=25^\circ\text{C}$ $T_c=75^\circ\text{C}$	35 25
			1ms	$T_c=25^\circ\text{C}$ $T_c=75^\circ\text{C}$	70 50
		$\leq I_c$			25
	Collector power dissipation	$P_C$	1 device	180	W
Brake	Collector-Emitter voltage	$V_{CES}$	1400	V	
	Gate-Emitter voltage	$V_{GES}$	$\pm 20$	V	
	Collector current	$I_c$	Continuous	$T_c=25^\circ\text{C}$ $T_c=75^\circ\text{C}$	25 15
				1ms	$T_c=25^\circ\text{C}$ $T_c=75^\circ\text{C}$
		$\leq I_c$			110
		Repetitive peak reverse voltage	$V_{RRM}$		1400
Converter	Repetitive peak reverse voltage	$V_{RRM}$	1600	V	
	Average output current	$I_O$	50Hz/60Hz sine wave	25	
	Surge current (Non-Repetitive)	$I_{FSM}$	$T_j=150^\circ\text{C}$ , 10ms	260	
	$I^2t$ (Non-Repetitive)	$I^2t$	half sine wave	338	
Operating junction temperature	$T_j$		+150	$^\circ\text{C}$	
Storage temperature	$T_{stg}$		-40 to +125	$^\circ\text{C}$	
Isolation voltage	$V_{iso}$	AC : 1 minute	between terminal and copper base *2	AC 2500	
			between thermistor and others *3	AC 2500	
Mounting screw torque			3.5 *1	N·m	

\*1 Recommendable value : 2.5 to 3.5 N·m (M5)

\*2 All terminals should be connected together when isolation test will be done.

\*3 Terminal 8 and 9 should be connected together. Terminal 1 to 7 and 10 to 24 should be connected together and shorted to copper base.

● Electrical characteristics (Tj=25°C unless otherwise specified)

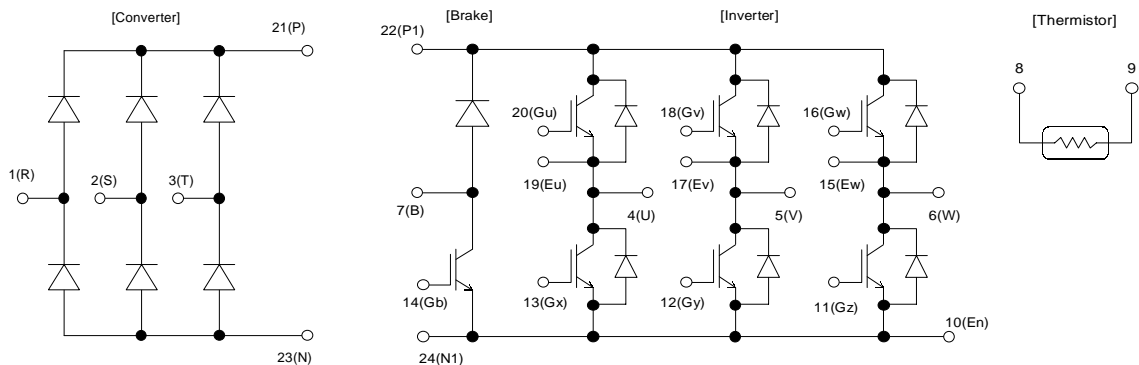
Item	Symbol	Condition	Characteristics			Unit		
			Min.	Typ.	Max.			
Inverter	Zero gate voltage collector current	ICES	VCE=1400V, VGE=0V		1.0	mA		
	Gate-Emitter leakage current	IGES	VCE=0V, VGE=±20V		0.2	µA		
	Gate-Emitter threshold voltage	VGE(th)	VCE=20V, Ic=25mA		5.5	7.2	8.5	V
	Collector-Emitter saturation voltage	VCE(sat)	VGE=15V, Ic=25A	chip	2.2		V	
				terminal	2.3	2.7		
	Input capacitance	Cies	VGE=0V, VCE=10V, f=1MHz		3000		pF	
	Turn-on time	ton	VCC=800V		0.35	1.2	µs	
		tr	Ic=25A		0.25	0.6		
		tr(i)	VGE=±15V		0.1			
	Turn-off	toff	RG=51Ω		0.45	1.0		
tf				0.08	0.3			
Forward on voltage	VF	IF=25A	chip	2.4		V		
			terminal	2.5	3.3			
Reverse recovery time of FRD	trr	IF=25A			0.35	µs		
Brake	Zero gate voltage collector current	ICES	VCEs=1400V, VGE=0V		1.0	mA		
	Gate-Emitter leakage current	IGES	VCE=0V, VGE=±20V		0.2	µA		
	Collector-Emitter saturation voltage	VCE(sat)	Ic=15A, VGE=15V	chip	2.2		V	
				terminal	2.3	2.7		
	Turn-on time	ton	VCC=800V		0.35	1.2	µs	
		tr	Ic=15A		0.25	0.6		
	Turn-off time	toff	VGE=±15V		0.45	1.0		
		tf	RG=82Ω		0.08	0.3		
	Reverse current	Irrm	VR=1400V			1.0	mA	
	Forward on voltage	VFM	IF=25A	chip	1.1		V	
terminal				1.2	1.5			
Reverse current	Irrm	VR=1600V			1.0	mA		
Resistance	R	T=25°C			5000	Ω		
			T=100°C	465	495		520	
B value	B	T=25/50°C			3305	K		
					3375		3450	

● Thermal resistance Characteristics

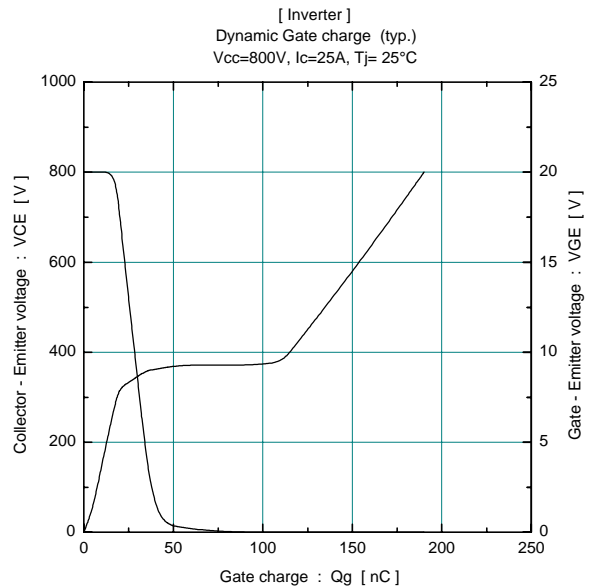
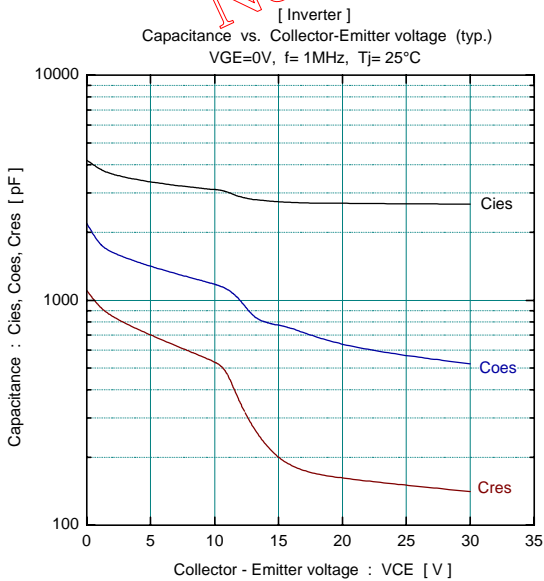
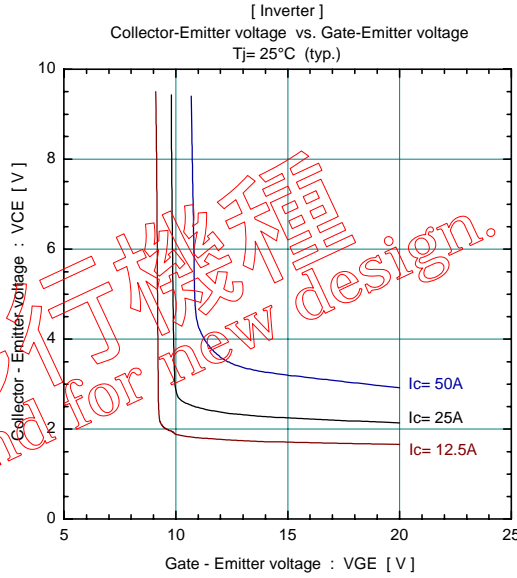
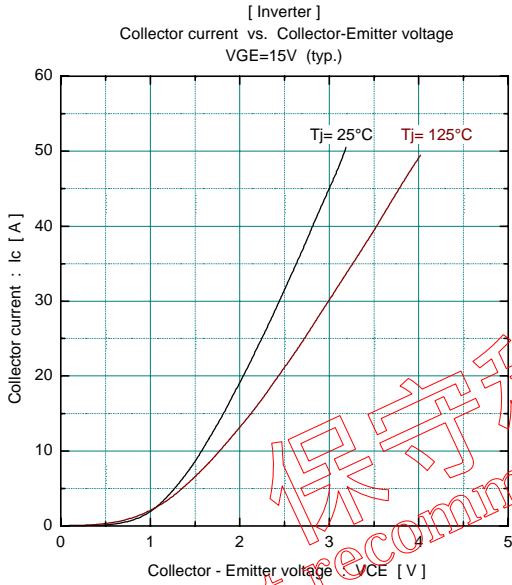
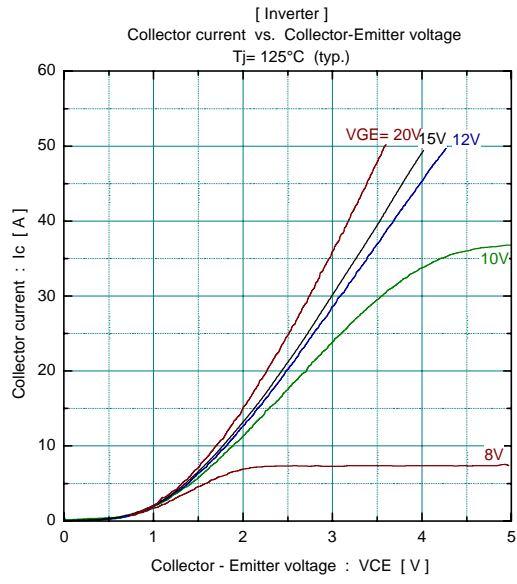
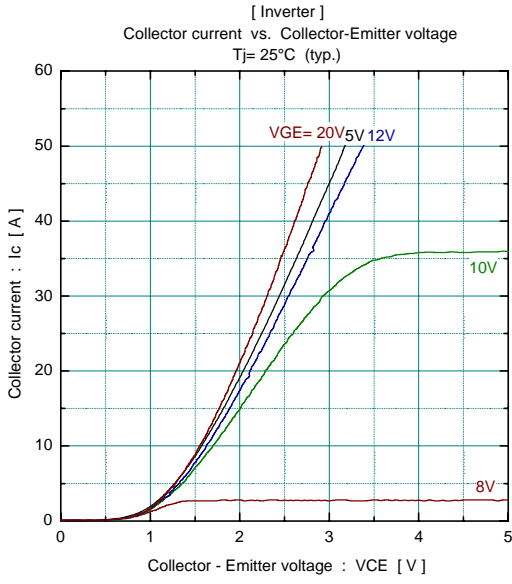
Item	Symbol	Condition	Characteristics			Unit
			Min.	Typ.	Max.	
Thermal resistance ( 1 device )	Rth(j-c)	Inverter IGBT			0.69	°C/W
		Inverter FWD			1.30	
		Brake IGBT			1.14	
		Converter Diode			0.90	
Contact thermal resistance	Rth(c-f)	With thermal compound		0.05		

\* This is the value which is defined mounting on the additional cooling fin with thermal compound

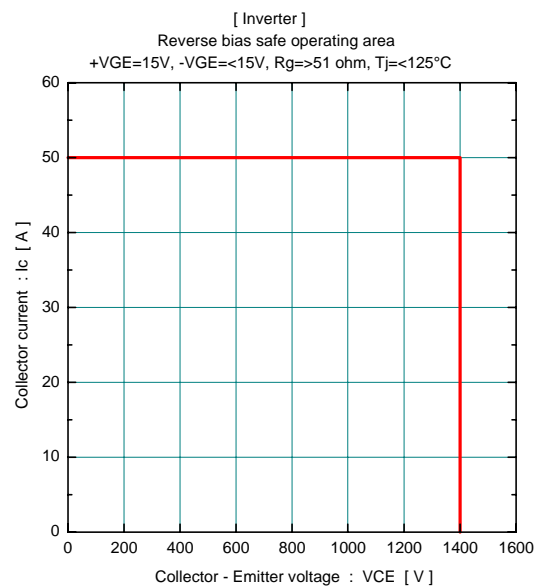
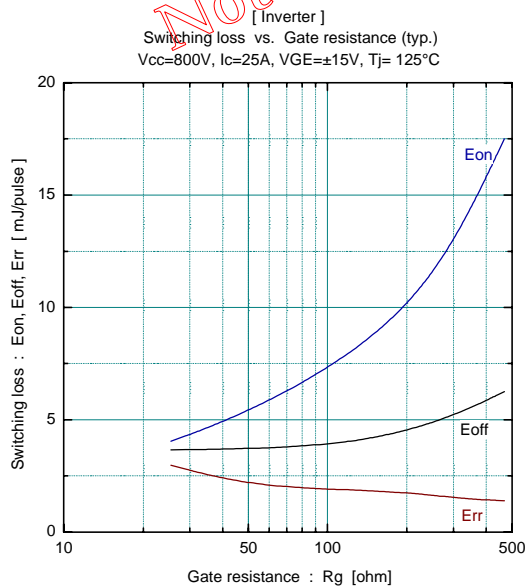
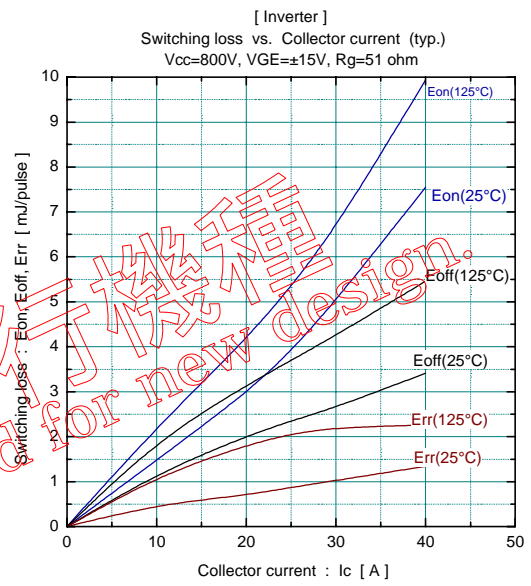
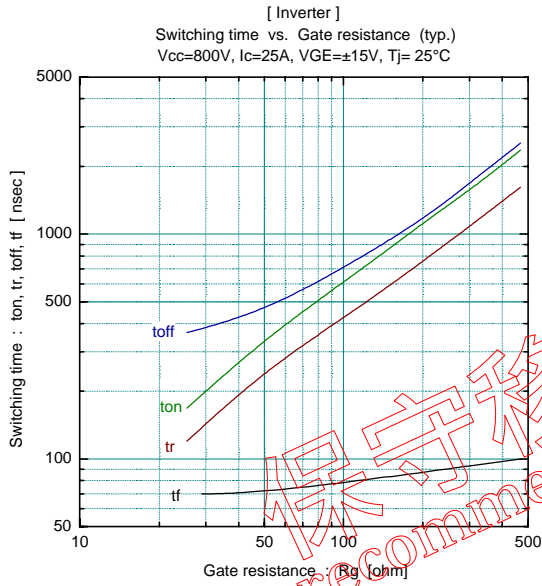
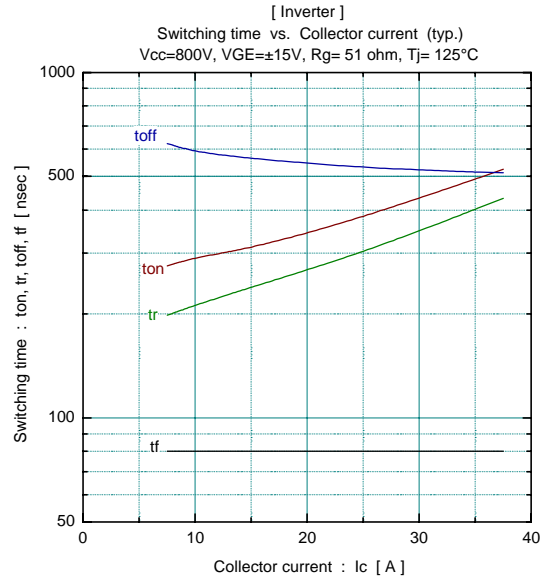
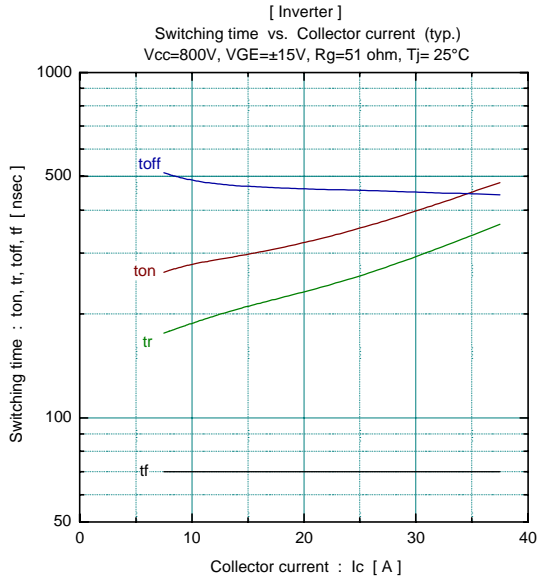
■ Equivalent Circuit Schematic

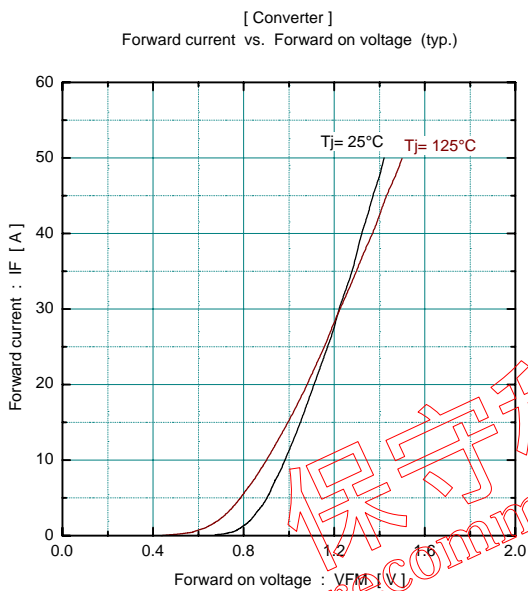
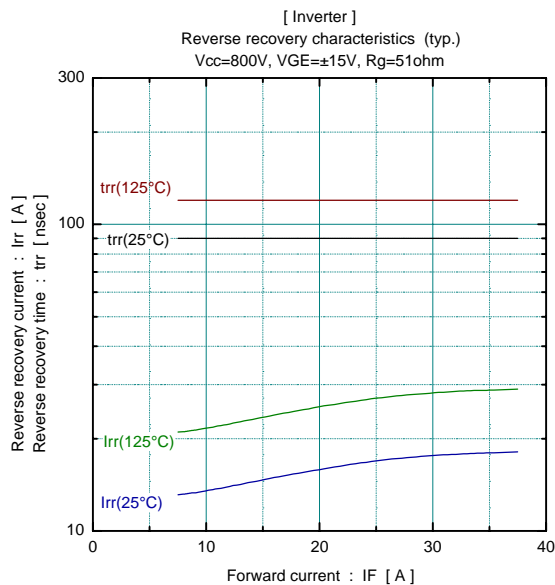
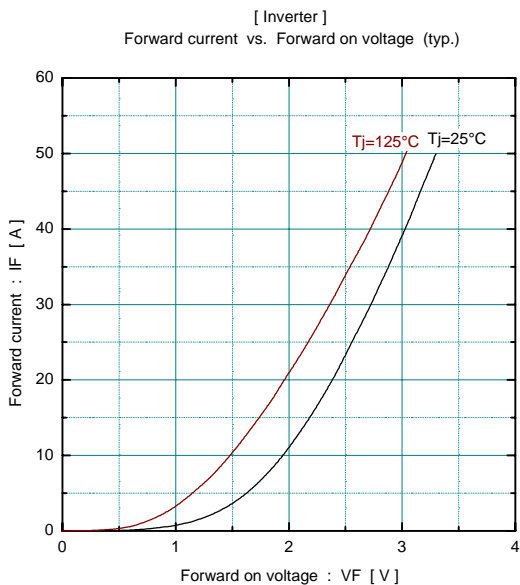


■ Characteristics (Representative)

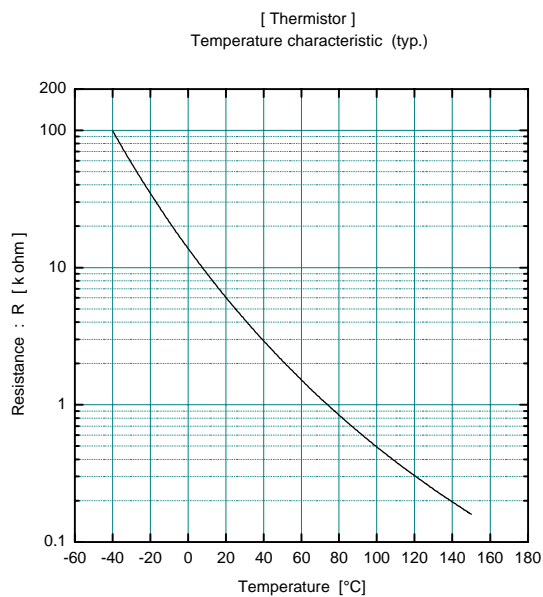
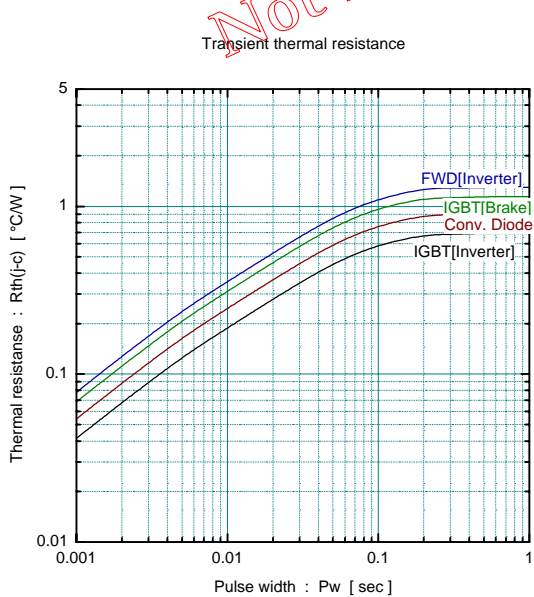


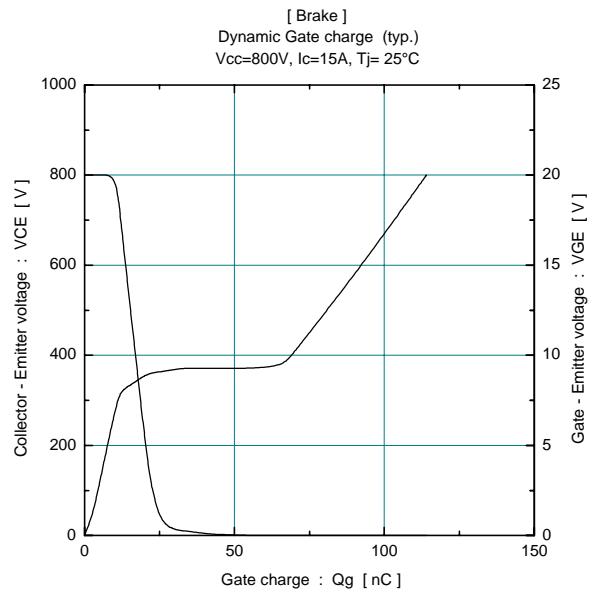
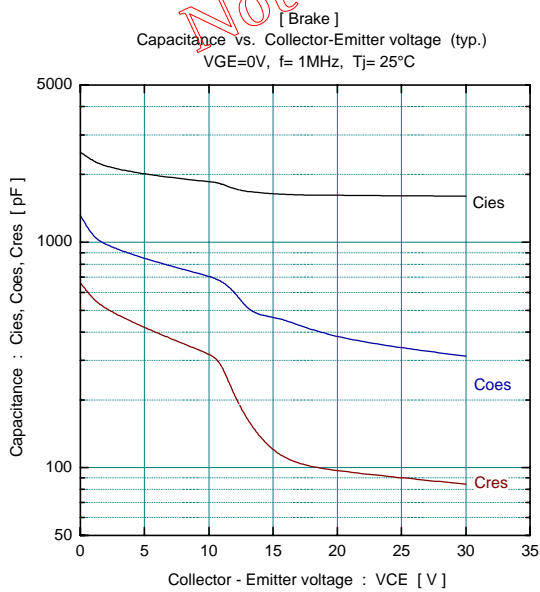
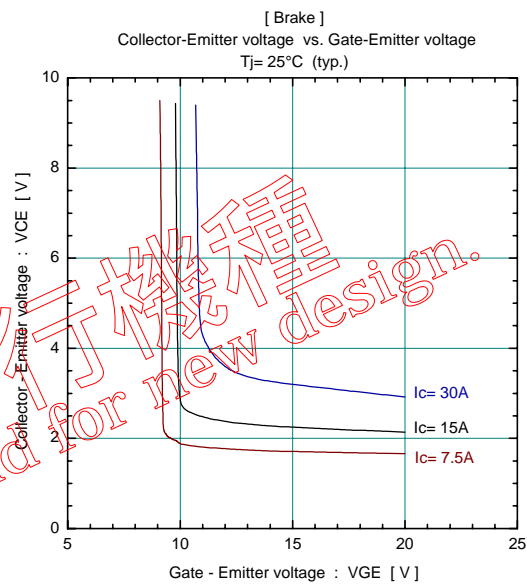
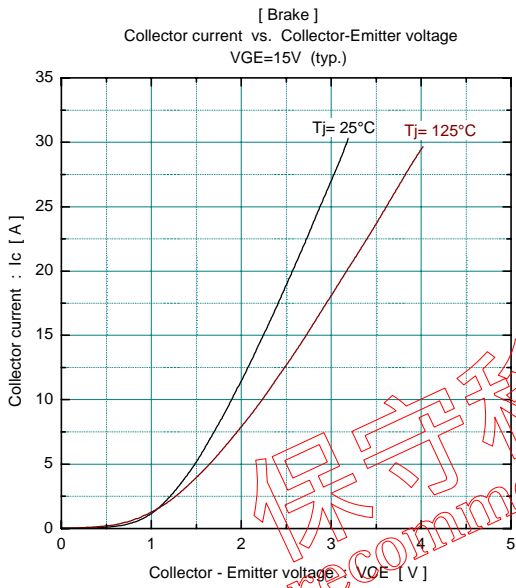
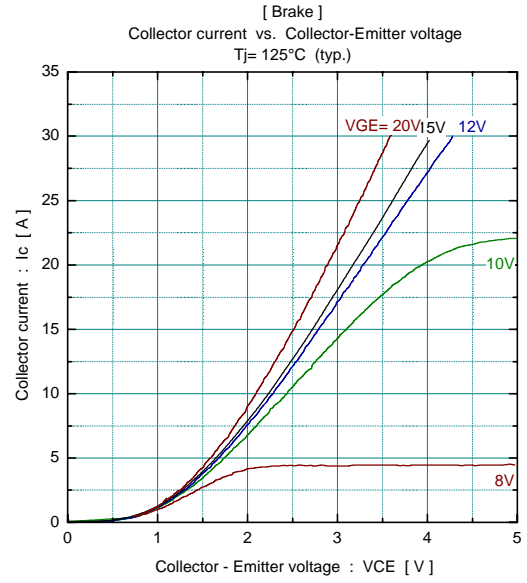
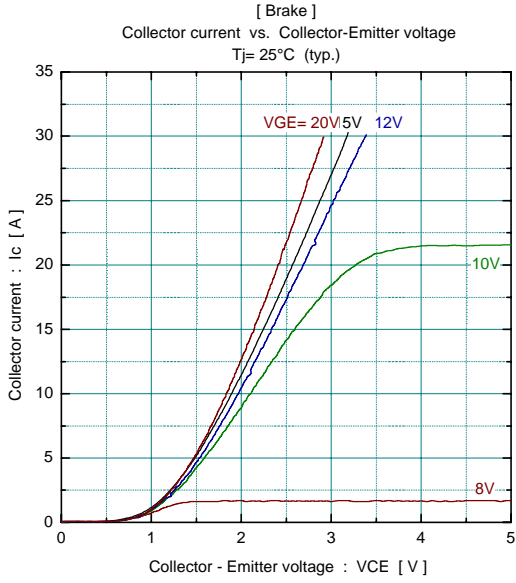
保守移行機種  
Not recommend for new design.





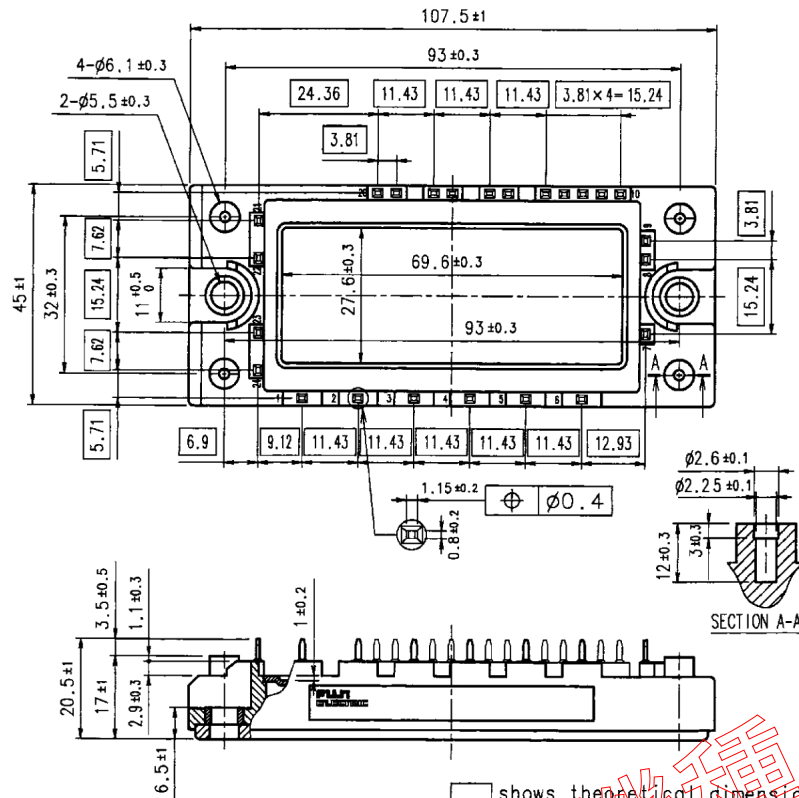
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■ Outline Drawings, mm



mass : 180g

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